

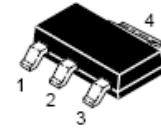
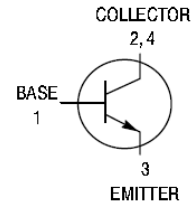
Features

- Epitaxial planar die construction
- Low current
- High voltage

HF

Mechanical Data

- Case: SOT-223
- Molding compound: UL flammability classification rating 94V-0
- Terminals: Tin-plated; solderability per MIL-STD-202, Method 208



SOT-223

Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
PZTA42	SOT-223	4000 pcs / Tape & Reel	A42

Maximum Ratings (@ T_A = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Collector-Base Breakdown Voltage	V _{CBO}	300	V
Collector-Emitter Breakdown Voltage	V _{CEO}	300	V
Emitter-Base Breakdown Voltage	V _{EBO}	6	V
Collector Current (Continuous)	I _C	0.5	A

Thermal Characteristics

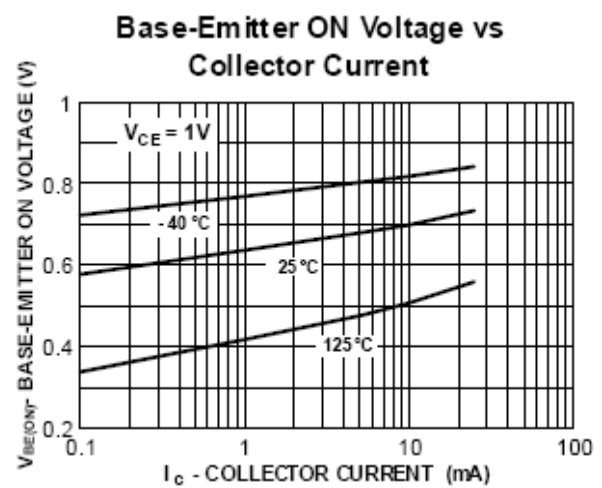
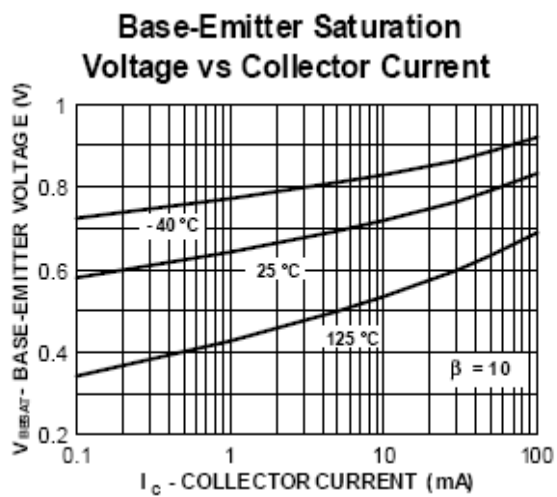
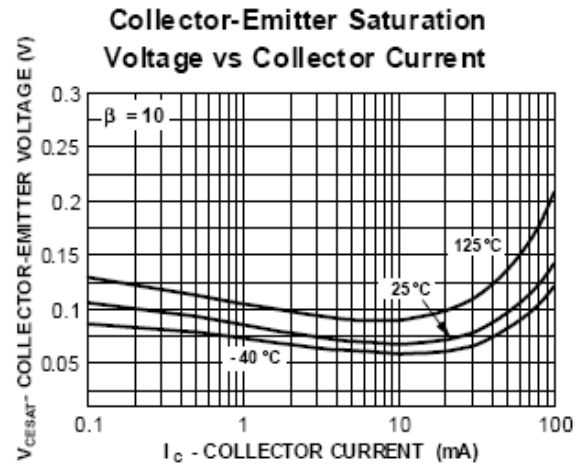
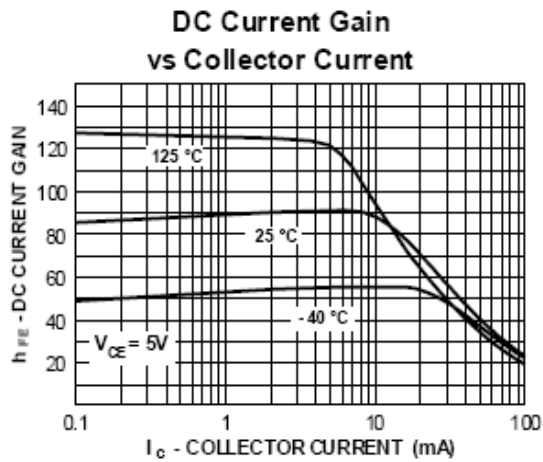
Parameter	Symbol	Value	Unit
Power Dissipation ^{*1}	P _D	1.5	W
Thermal Resistance (Junction-to-Ambient) ^{*1}	R _{θJA}	83.3	°C/W
Junction Temperature	T _J	-55 ~ +150	°C
Storage Temperature Range	T _{STG}	-55 ~ +150	°C

Note1: Device mounted on a FR-4 glass epoxy printed circuit board 1.575 in x 1.575 in x 0.0625 in; mounting pad for the collector lead = 0.93 sq in.

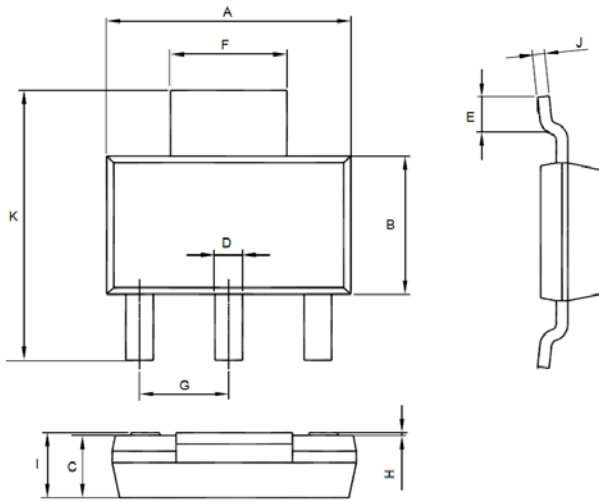
Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 100\mu\text{A}, I_E = 0$	300	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 1\text{mA}, I_B = 0$	300	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 100\mu\text{A}, I_C = 0$	6	-	-	V
Collector Cut-off Current	I_{CBO}	$V_{CB} = 200\text{V}, I_E = 0$	-	-	100	nA
Base Cut-off Current	I_{EBO}	$V_{EB} = 6\text{V}, I_C = 0$	-	-	100	nA
DC Current Gain	h_{FE}	$V_{CE} = 10\text{V}, I_C = 1\text{mA}$	25	-	-	-
		$V_{CE} = 10\text{V}, I_C = 10\text{mA}$	40	-	-	-
		$V_{CE} = 10\text{V}, I_C = 30\text{mA}$	40	-	-	-
Collector-emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 20\text{mA}, I_B = 2\text{mA}$	-	-	0.5	V
Base-emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = 20\text{mA}, I_B = 2\text{mA}$	-	-	0.9	V
Output Capacitance	C_{OBO}	$V_{CB} = 20\text{V}, I_E = 0, f = 1\text{MHz}$	-	-	3	pF
Transition Frequency	f_T	$I_C = 10\text{mA}, V_{CE} = 20\text{V}$ $f = 100\text{MHz}$	50	-	-	MHZ

Ratings and Characteristic Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)



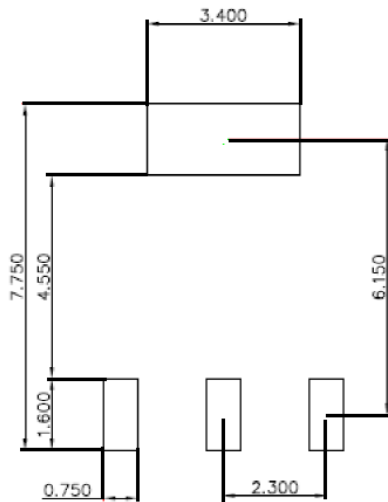
Package Outline Dimensions (Unit: mm)



SOT-223		
Dimension	Min.	Max.
A	6.10	6.50
B	3.30	3.70
C	1.50	1.70
D	0.66	0.82
E	0.90	1.15
F	2.90	3.10
G	2.20	2.40
H	0.02	0.10
I	1.52	1.80
J	0.20	0.40
K	6.70	7.30

Mounting Pad Layout (Unit: mm)

SOT-223



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